NSN 5961-00-584-2452

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View Online at https://aerobasegroup.com/nsn/5961-00-584-2452 **Inclosure Material:** Metal **Overall Length:** 1.120 inches **End Application:** Wasp class Ihd, tarawa class Iha. Electric power generation system. Countermeasures systems. **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: T0-93 **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case and mounting hardware **Overall Width Across Flats:** 1.250 inches **Thread Size:** 0.750 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 800.0 reverse voltage, peak and 3.0 gate trigger voltage, dc **Current Rating Per Characteristic:** 250.00 milliamperes forward current, total rms preset **Power Rating Per Characteristic:** 2.0 watts small-signal input power, common-collector blank **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: pnpn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 insulated wire lead w/terminal lug Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No

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